

# **EMS101-P**

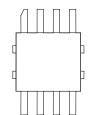
#### **ISSUED DATE: 07-18-03**

### PRELIMINARY DATA SHEET

## DC - 6 GHz GaAs MMIC SPDT SWITCH

### **FEATURES**

- BROADBAND PERFORMANCE
- HIGH ISOLATION
- LOW INSERTION LOSS
- LOW DC POWER CONSUMPTION
- FAST SWITCHING SPEED
- SI3N4 PASSIVATION
- ADVANCED EPITAXIAL HETEROJUNCTION PROFILE PROVIDES HIGH RELIABILITY



## Description

The EMA101-P is a GaAs IC single pole double throw broadband RF switch. It can be used for broadband communications and instrument application. This device is packaged in a SO-8 surface mount package and internally it can be terminated with 50ohm load or short circuit based on requirement .The switch is controlled by the application of 0V/-5V signals to the control lines in accordance with the truth table below.

## **ELECTRICAL CHARACTERISTICS (T<sub>a</sub> = 25 °C)**

SYMBOL	PARAMETERS/TEST CONDITIONS		MIN	TYP	MAX	UNIT
F	Operating frequency Range		DC		6	GHz
P1dB	Input Power at 1dB Gain compression	0/-5V Control; 50MHz		20		dBm
		0/-5V Control; 2GHz		26		dBm
Ls	Insertion Loss (DC-3GHz)			1	1.5	dB
		(3-6GHz)		1.5	2	dB
ISO	Isolation	(DC-3GHz)		30	32	dB
		(3-6GHz)		25	28	dB
<b>VSWR</b> in	Input VSWR		1.8			
VSWR out	Output VSWR		1.8			
т	Switching Speed (	50% control to 10%/90%RF)		3	8	nS

#### Note:

- 1. VSWR measured in low loss switch state
- 2. P1dB measured input power at which insertion loss compressed by 1dB
- 3. All measurement made in a 500hm system

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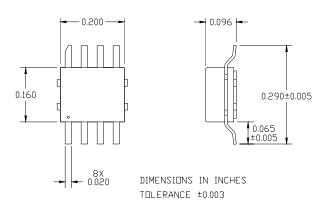
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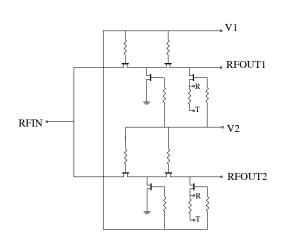
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### **Package Outline**



### **Electrical Schematic**



Ground R: Reflective Ground T: Terminated

### **Pin Description**

Pin	Function		
1	Ground		
2	RF IN		
3	Ground		
4	Ground		
5	RF OUT1		
6	Control V1		
7	Control V2		
8	RF OUT2		

### **Switch Diagram**

V1	V2	RFIN-RFOUT1	RFIN-RFOUT2
0V	-5V	Low Loss	Isolated
-5V	0V	Isolated	Low Loss

### **Absolute maximum Rating**

RF input power 31dBm

Operating temperature -40°C to +85°C Storage temperature -65°C to 150°C

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